

# PS8502, PS8502L1, PS8502L2, PS8502L3

HIGH SPEED ANALOG OUTPUT TYPE 8-PIN PHOTOCOUPLER

R08DS0263EJ0100 Rev.1.00 Dec 23, 2021

#### DESCRIPTION

The PS8502, PS8502L1, PS8502L2 and PS8502L3 are 8-pin high speed photocouplers containing an AIGaAs LED on input side and a PN photodiode and a high speed amplifier transistor on output side on one chip.

The PS8502 is in a plastic DIP (Dual In-line Package).

The PS8502L1 is lead bending type for long creepage distance.

The PS8502L2 is lead bending type for long creepage distance (Gull-wing) for surface mount.

The PS8502L3 is lead bending type (Gull-wing) for surface mounting.

#### **FEATURES**

- Long creepage distance (8 mm MIN.: PS8502L1, PS8502L2)
- High common mode transient immunity (CM<sub>H</sub>, CM<sub>L</sub> = ±15 kV/µs MIN)
- High supply voltage (Vcc = 35 V MAX.)
- High speed response (tphl, tplh = 0.8 μs MAX.)
- High isolation voltage (BV = 5 000 Vr.m.s.)
- · TTL, CMOS compatible with a resistor
- Ordering number of tape product : PS8502L2-E3 : 1 000 pcs/reel

: PS8502L3-E3 : 1 000 pcs/reel

- Pb-Free product
- Safety standards
- UL approved: UL1577, Double protection
- CSA approved: CAN/CSA-C22.2 No.62368-1, Reinforced insulation
- BSI approved: BS EN 62368-1, Reinforced insulation
- SEMKO approved: EN 62368-1, IEC 62368-1, Reinforced insulation
- NEMKO approved: EN 62368-1, Reinforced insulation
- DEMKO approved: EN 62368-1, Reinforced insulation
- FIMKO approved: EN 62368-1, Reinforced insulation
- VDE approved: DIN EN 60747-5-5 (Option)

# PIN CONNECTION (Top View) 1. NC 2. Anode 3. Cathode 4. NC 5. Emitter 6. Vo 7. NC 8. Vcc

#### **APPLICATIONS**

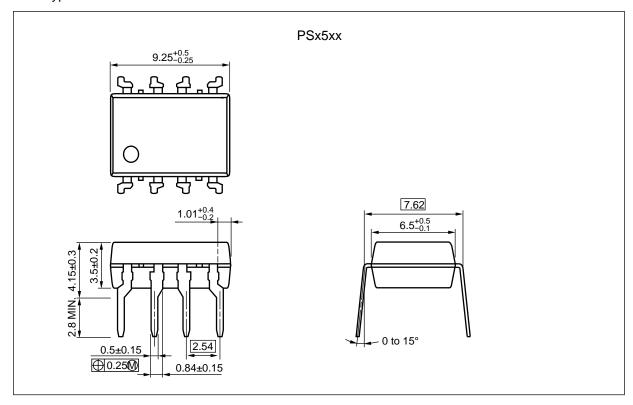
- Interface for measurement or control equipment
- Substitutions for relays and pulse transformers
- Modem, communications device
- General purpose inverter

Start of mass production

Jun.2006

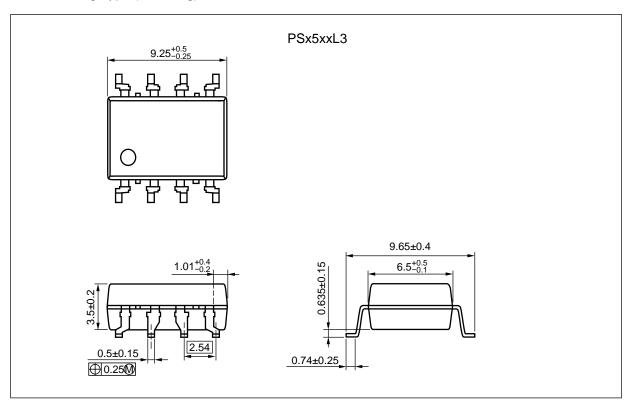
# PACKAGE DIMENSIONS (UNIT: mm)

DIP Type

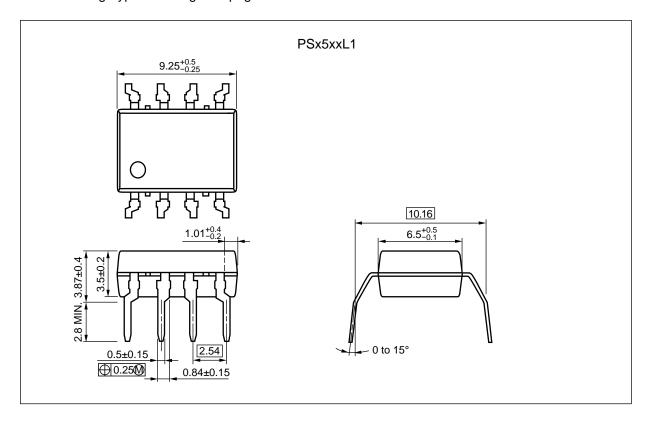


Weight: 0.55g (typ.)

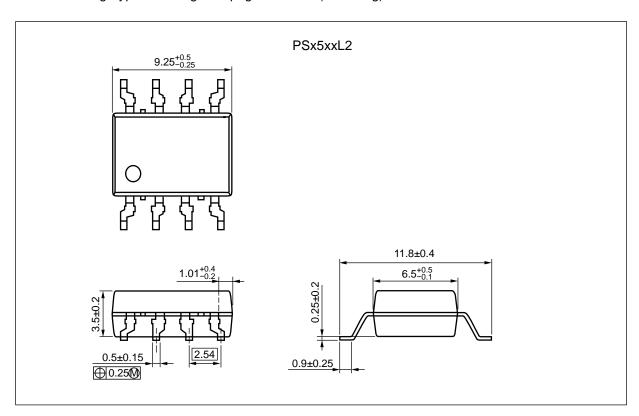
# Lead Bending Type (Gull-wing) For Surface Mount



Lead Bending Type For Long Creepage Distance



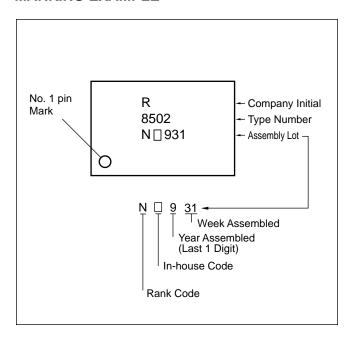
Lead Bending Type For Long Creepage Distance (Gull-wing) For Surface Mount



# PHOTOCOUPLER CONSTRUCTION

Parameter	PS8502, PS8502L3	PS8502L1, PS8502L2
Air Distance (MIN.)	7 mm	8 mm
Creepage Distance (MIN.)	7 mm	8 mm
Isolation Distance (MIN.)	0.4 mm	0.4 mm

#### **MARKING EXAMPLE**



# **ORDERING INFORMATION**

Part Number	Order Number	Solder Plating Specification	Packing Style	Safety Standard Approval	Application Part Number *1
PS8502	PS8502-AX	Pb-Free	Magazine case 50 pcs	Standard products	PS8502
PS8502L1	PS8502L1-AX	(Ni/Pd/Au)		(UL, CSA, BSI, SEMKO, NEMKO, DEMKO, FIMKO approved)	PS8502L1
PS8502L2	PS8502L2-AX				PS8502L2
PS8502L3	PS8502L3-AX				PS8502L3
PS8502L2-E3	PS8502L2-E3-AX		Embossed Tape 1 000 pcs/reel		PS8502L2
PS8502L3-E3	PS8502L3-E3-AX				PS8502L3
PS8502-V	PS8502-V-AX		Magazine case 50 pcs	UL, CSA, BSI,	PS8502
PS8502L1-V	PS8502L1-V-AX			SEMKO, NEMKO, FIMKO, DEMKO, DIN EN 60747-5-5 approved	PS8502L1
PS8502L2-V	PS8502L2-V-AX				PS8502L2
PS8502L3-V	PS8502L3-V-AX				PS8502L3
PS8502L2-V-E3	PS8502L2-V-E3-AX		Embossed Tape 1 000 pcs/reel		PS8502L2
PS8502L3-V-E3	PS8502L3-V-E3-AX				PS8502L3

Notes\*: 1. For the application of the Safety Standard, following part number should be used.

# ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = 25 °C, unless otherwise specified)

	Parameter	Symbol	Ratings	Unit
Diode	Forward Current *1	lF	25	mA
	Reverse Voltage	VR	5	V
Detector	Supply Voltage	Vcc	35	V
	Output Voltage	Vo	35	V
	Output Current	lo	8	mA
	Power Dissipation *2	Pc	100	mW
Isolation Vo	oltage *3	BV	5 000	Vr.m.s.
Operating /	Ambient Temperature	TA	−55 to +100	°C
Storage Te	mperature	T <sub>stg</sub>	−55 to +125	°C

Notes\*: 1. Reduced to 0.33 mA/ $^{\circ}$ C at T<sub>A</sub> = 70  $^{\circ}$ C or more.

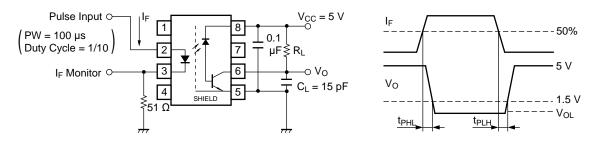
- 2. Reduced to 2.0 mW/°C at  $T_A = 75$  °C or more.
- 3. AC voltage for 1 minute at  $T_A$  = 25 °C, RH = 60% between input and output. Pins 1-4 shorted together, 5-8 shorted together.

# ELECTRICAL CHARACTERISTICS ( $T_A = 25$ °C)

	Parameter	Symbol	Conditions	MIN.	TYP.*1	MAX.	Unit
Diode	Forward Voltage	VF	IF = 16 mA		1.7	2.2	V
	Reverse Current	IR	V <sub>R</sub> = 3 V			10	μА
	Forward Voltage Temperature Coefficent	△VF/△TA	IF = 16 mA		-2.1		mV/°C
	Terminal Capacitance	Ct	V = 0 V, f = 1 MHz		30		pF
Detector	High Level Output Current	Іон (1)	$I_F = 0 \text{ mA}, V_{CC} = V_0 = 5.5 \text{ V}$		3	500	nA
	High Level Output Current	Іон (2)	IF = 0 mA, Vcc = Vo = 35 V			100	μА
	Low Level Output Voltage	Vol	IF = 16 mA, Vcc = 4.5 V, Io = 2.4 mA		0.15	0.4	V
	Low Level Supply Current	Iccl	IF = 16 mA, Vo = Open, Vcc = 35 V		150		μА
	High Level Supply Current	Іссн	IF = 0 mA, Vo = Open, Vcc = 35 V		0.01	1	μА
Coupled	Current Transfer Ratio	CTR	IF = 16 mA, Vcc = 4.5 V, Vo = 0.4 V	15			%
	Isolation Resistance	Rı-o	V <sub>I-O</sub> = 1 kV <sub>DC</sub>	10 <sup>11</sup>			Ω
	Isolation Capacitance	CI-O	V = 0 V, f = 1 MHz		0.7		pF
	Propagation Delay Time $(H \to L)^{*2}$	tрнL	IF = 16 mA, $Vcc$ = 5 V, $R_L$ = 1.9 $k\Omega$		0.22	0.8	μS
	Propagation Delay Time $(L \rightarrow H)^{*2}$	tрLН	I <sub>F</sub> = 16 mA, $Vcc$ = 5 V, $R_L$ = 1.9 $k\Omega$		0.35	0.8	μЅ
	Common Mode Transient Immunity at High Level Output <sup>*3</sup>	СМн	$I_F = 0 \text{ mA, } V_{CC} = 5 \text{ V, } V_{CM} = 1.5 \text{ kV,}$ $R_L = 4.1 \text{ k}\Omega$	15			kV/μs
	Common Mode Transient Immunity at Low Level Output <sup>'3</sup>	CML	IF = 16 mA, Vcc = 5 V, VcM = 1.5 kV, RL = 4.1 k $\Omega$	-15			kV/μs

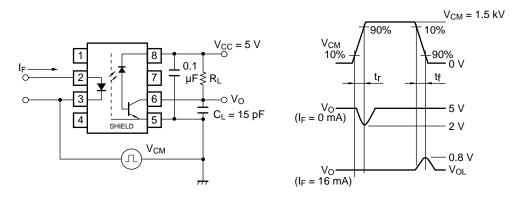
Notes\*: 1. Typical values at  $T_A = 25$  °C.

#### 2. Test circuit for propagation delay time



Remark: C<sub>L</sub> includes probe and stray wiring capacitance.

#### 3. Test circuit for common mode transient immunity



Remark:  $C_L$  includes probe and stray wiring capacitance.

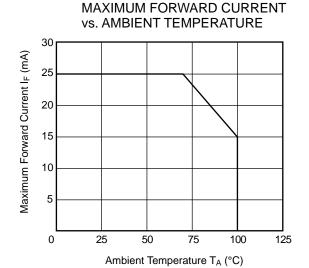
### **USAGE CAUTIONS**

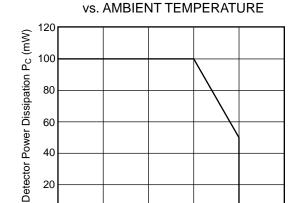
- 1. This product is weak for static electricity by designed with high-speed integrated circuit so protect against static electricity when handling.
- 2. By-pass capacitor of more than 0.1  $\mu$ F is used between V<sub>CC</sub> and GND near device. Also, ensure that the distance between the leads of the photocoupler and capacitor is no more than 10 mm.
- 3. Pins 1, 4 (which is an NC\*1 pin) can either be connected directly to the GND pin on the LED side or left open. Also, Pin 7 (which is an NC\*1 pin) can either be connected directly to the GND pin on the detector side or left open.

Unconnected pins should not be used as a bypass for signals or for any other similar purpose because this may degrade the internal noise environment of the device.

- \*1 NC: Non-Connection (No Connection)
- 4. Avoid storage at a high temperature and high humidity.
- 5. Avoid cleaning with Freon based or halogen-based (chlorinated etc.) solvents.
- 6. Do not use fixing agents or coatings containing halogen-based substances.

# TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25 °C unless otherwise specified)





50

20

0

25

**DETECTOR POWER DISSIPATION** 

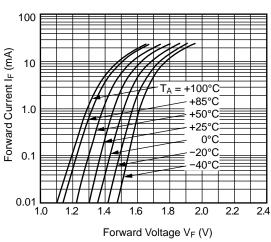
Ambient Temperature T<sub>A</sub> (°C)

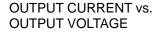
75

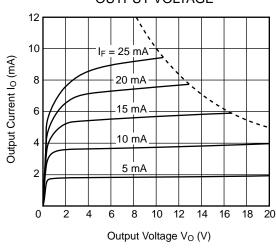
100

125

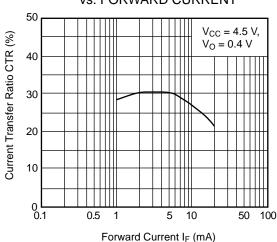




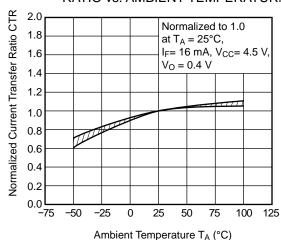




#### **CURRENT TRANSFER RATIO** vs. FORWARD CURRENT



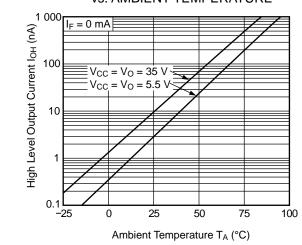
#### NORMALIZED CURRENT TRANSFE RATIO vs. AMBIENT TEMPERATURI



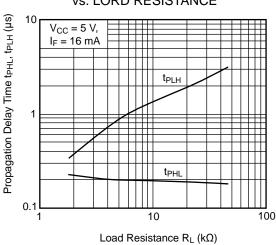
Remark The graphs indicate nominal characteristics.

#### OUTPUT VOLTAGE vs. FORWARD CURRENT $V_{CC} = 5 V$ $V_{CC}$ 6 Output Voltage Vo (V) 5 4 3 $R_L=1.9~k\dot{\Omega}$ 2 5.5 kΩ 0 6 8 10 12 14 16 18 2 4 Forward Current I<sub>F</sub> (mA)

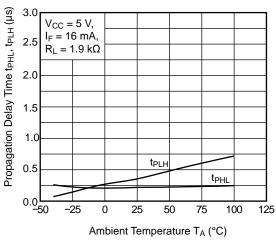
# HIGH LEVEL OUTPUT CURRENT vs. AMBIENT TEMPERATURE





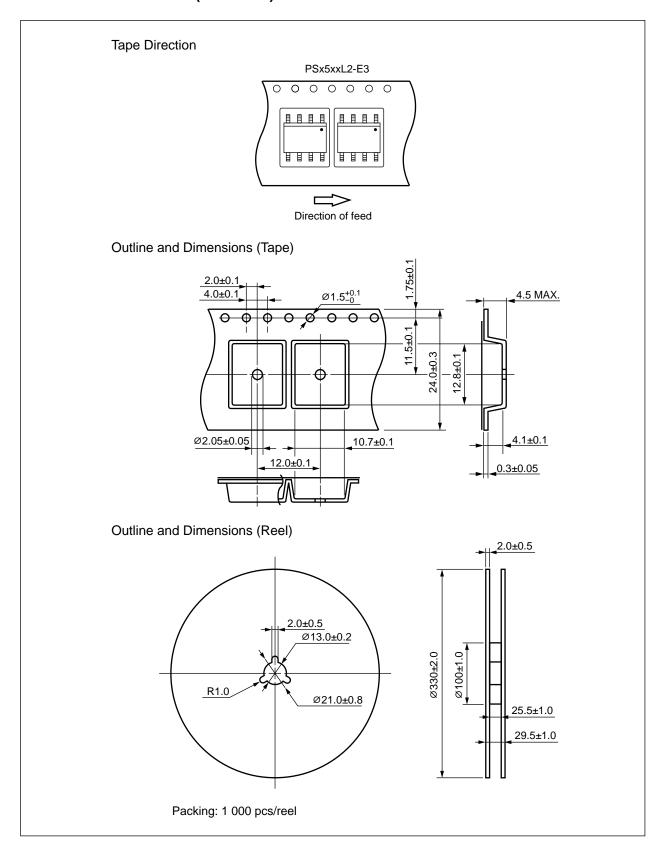


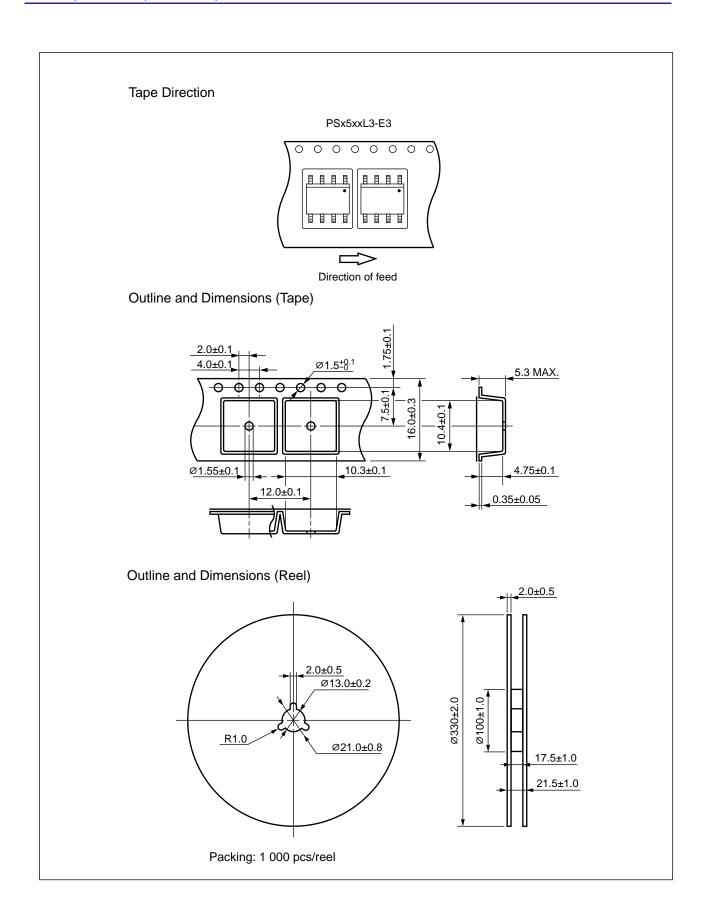
# PROPAGATION DELAY TIME vs. AMBIENT TEMPERATURE



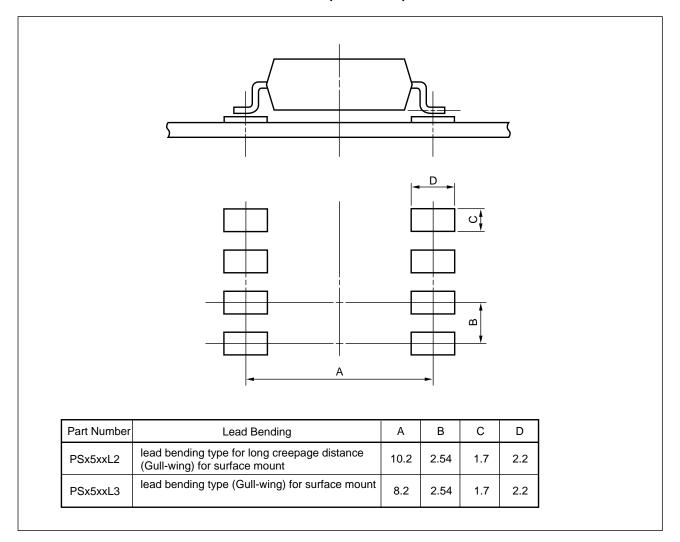
Remark The graphs indicate nominal characteristics.

# **TAPING SPECIFICATIONS (UNIT: mm)**





# RECOMMENDED MOUNT PAD DIMENSIONS (UNIT: mm)



Remark All dimensions in this figure must be evaluated before use.

#### **NOTES ON HANDLING**

- 1. Recommended soldering conditions
  - (1) Infrared reflow soldering

• Peak reflow temperature 260 °C or below (package surface temperature)

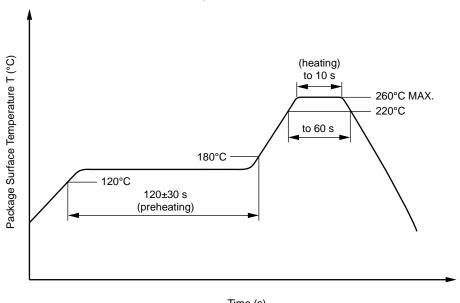
Time of peak reflow temperature
 Time of temperature higher than 220 °C
 10 seconds or less
 60 seconds or less

• Time to preheat temperature from 120 to 180 °C 120±30 s

Number of reflowsFluxRosin

Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

# Recommended Temperature Profile of Infrared Reflow



Time (s)

(2) Wave soldering

• Temperature 260 °C or below (molten solder temperature)

• Time 10 seconds or less

• Preheating conditions 120 °C or below (package surface temperature)

Number of times
 Flux
 One (Allowed to be dipped in solder including plastic mold portion.)
 Rosin flux containing small amount of chlorine (The flux with a maximum

chlorine content of 0.2 Wt% is recommended.)

(3) Soldering by Soldering Iron

Peak Temperature (lead part temperature)
 Time (each pins)
 350 °C or below
 3 seconds or less

• Flux Rosin flux containing small amount of chlorine

(The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

- (a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead
- (b) Please be sure that the temperature of the package would not be heated over 100 °C
- (4) Cautions
  - Flux Cleaning

Avoid cleaning with Freon based or halogen-based (chlorinated etc.) solvents.

• Do not use fixing agents or coatings containing halogen-based substances.

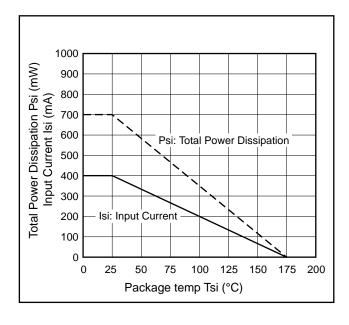
#### 2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output or between  $V_{CC}$ -emitters at startup, the output side may enter the on state, even if the voltage is within the absolute maximum ratings.

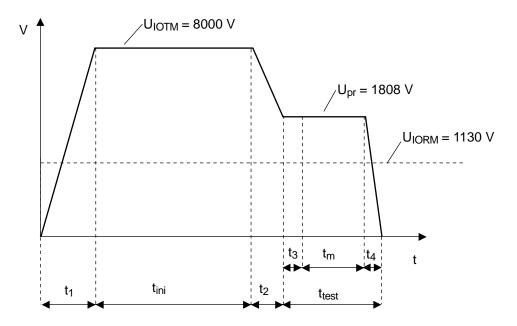
# SPECIFICATION OF VDE MARKS LICENSE DOCUMENT

Parameter	Symbol	Rating	Unit
Climatic test class (IEC 60068-1/DIN EN 60068-1)		55/100/21	
Dielectric strength			
maximum operating isolation voltage	UIORM	1 130	Vpeak
Test voltage (partial discharge test, procedure a for type test and random test)	Upr	1 695	V peak Vpeak
$U_{pr} = 1.6 \times U_{IORM}, P_d < 5 pC$	<b>Ο</b> ρι	1 000	• poak
Test voltage (partial discharge test, procedure b for all devices)	Upr	2 119	Vpeak
U <sub>pr</sub> = 1.875 × U <sub>IORM</sub> , P <sub>d</sub> < 5 pC	Орі	2 113	v peak
Highest permissible overvoltage	Uютм	8 000	$V_{peak}$
Degree of pollution (DIN EN 60664-1 VDE 0110 Part 1)		2	
Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303 Part 11))	CTI	175	
Material group (DIN EN 60664-1 VDE 0110 Part 1)		III a	
Storage temperature range	Tstg	-55 to +125	°C
Operating temperature range	TA	-55 to +100	°C
Isolation resistance, minimum value			
V <sub>IO</sub> = 500 V dc at T <sub>A</sub> = 25 °C	Ris MIN.	10 <sup>12</sup>	Ω
V <sub>IO</sub> = 500 V dc at T <sub>A</sub> MAX. at least 100 °C	Ris MIN.	10 <sup>11</sup>	Ω
Safety maximum ratings (maximum permissible in case of fault, see thermal			
derating curve)			
Package temperature	Tsi	175	°C
Current (input current I <sub>F</sub> , Psi = 0)	Isi	400	mA
Power (output or total power dissipation)	Psi	700	mW
Isolation resistance			
Vio = 500 V dc at Ta = Tsi	Ris MIN.	10 <sup>9</sup>	Ω

# Dependence of maximum safety ratings with package temperature



# Method a) Destructive Test, Type and Sample Test



 $t_1$ ,  $t_2 = 1$  to 10 sec

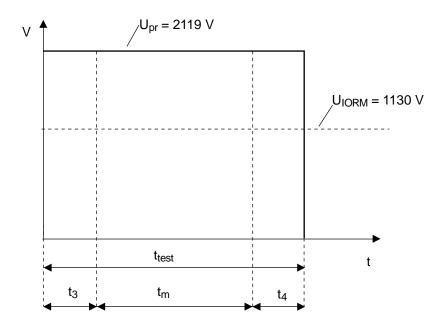
 $t_3, t_4 = 1 sec$ 

 $t_{\text{m(PARTIAL DISCHARGE)}} = 10 \text{ sec}$ 

 $t_{\text{test}} = 12 \text{ sec}$ 

 $t_{ini} = 60 \text{ sec}$ 

# Method b) Non-destructive Test, 100% Production Test



 $t_3$ ,  $t_4 = 0.1 sec$ 

 $t_{\text{m(PARTIAL DISCHARGE)}} = 1.0 \text{ sec}$ 

 $t_{test} = 1.2 \text{ sec}$ 

Caution

**GaAs Products** 

This product uses gallium arsenide (GaAs).

GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.

- Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
  - Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
- 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
- Do not burn, destroy, cut, crush, or chemically dissolve the product.
- Do not lick the product or i any way allow it to enter the mouth.

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